

### NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4815 is a power transistor developed for high-speed switching and features low  $V_{CE(sat)}$  and high  $h_{FE}$ . This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, this transistor is available for the auto mount in the radial taping specifications and for mounting cost reduction.

#### FEATURES

- High  $h_{FE}$  and low  $V_{CE(sat)}$ :  
 $V_{CE(sat)} \leq 0.3 \text{ V}$  @  $I_C = 3.0 \text{ A}$ ,  $I_B = 0.15 \text{ A}$   
 $h_{FE} \geq 100$  @  $V_{CE} = 2.0 \text{ V}$ ,  $I_C = 1.0 \text{ A}$
- Available for auto mount in radial taping specifications

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	100	V
Collector to emitter voltage	$V_{CEO}$	60	V
Emitter to base voltage	$V_{EBO}$	7.0	V
Collector current (DC)	$I_{C(DC)}$	5.0	A
Collector current (pulse)	$I_{C(pulse)}^*$	10	A
Base current (DC)	$I_{B(DC)}$	2.5	A
Total power dissipation	$P_T$	1.8	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

\*  $PW \leq 300 \mu s$ , duty cycle  $\leq 10\%$

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 Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

**ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	$V_{CE0(SUS)}$	$I_C = 5.0 A, I_B = 0.5 A, L = 1 mH$	60			V
Collector to emitter voltage	$V_{CEX(SUS)}$	$I_C = 2.5 A, I_{B1} = -I_{B2} = 0.25 A$ $V_{BE(OFF)} = -1.5 V, L = 180 \mu H, \text{Clamped}$	60			V
Collector cutoff current	$I_{CBO}$	$V_{CB} = 100 V, I_E = 0$			10	$\mu A$
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 7.0 V, I_C = 0$			10	$\mu A$
DC current gain	$h_{FE1}^*$	$V_{CE} = 2.0 V, I_C = 0.5 A$	100			
DC current gain	$h_{FE2}^*$	$V_{CE} = 2.0 V, I_C = 1.0 A$	100	200	400	
DC current gain	$h_{FE3}^*$	$V_{CE} = 2.0 V, I_C = 3.0 A$	60			
Collector saturation voltage	$V_{CE(sat)1}^*$	$I_C = 3.0 A, I_B = 0.15 A$		0.15	0.3	V
Collector saturation voltage	$V_{CE(sat)2}^*$	$I_C = 4.0 A, I_B = 0.2 A$		0.3	0.5	V
Base saturation voltage	$V_{BE(sat)1}^*$	$I_C = 3.0 A, I_B = 0.15 A$		0.9	1.2	V
Base saturation voltage	$V_{BE(sat)2}^*$	$I_C = 4.0 A, I_B = 0.2 A$		1.2	1.5	V
Collector capacitance	$C_{ob}$	$V_{CB} = 10 V, I_E = 0, f = 1.0 MHz$		70		pF
Gain bandwidth product	$f_T$	$V_{CE} = 10 V, I_C = 0.5 A$		150		MHz
Turn-on time	$t_{on}$	$I_C = 3.0 A, R_L = 17 \Omega,$ $I_{B1} = -I_{B2} = 0.15 A, V_{CC} \cong 50 V$ Refer to the test circuit.		0.1		$\mu s$
Storage time	$t_{stg}$			1.0		$\mu s$
Fall time	$t_f$			0.25		$\mu s$

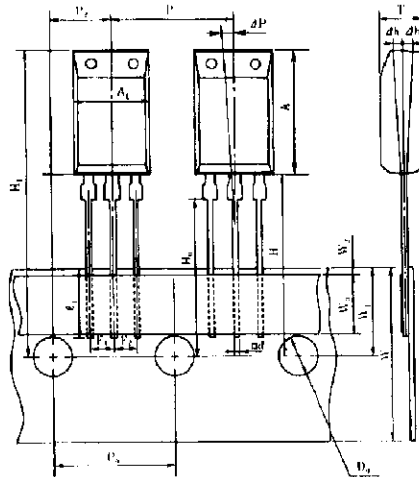
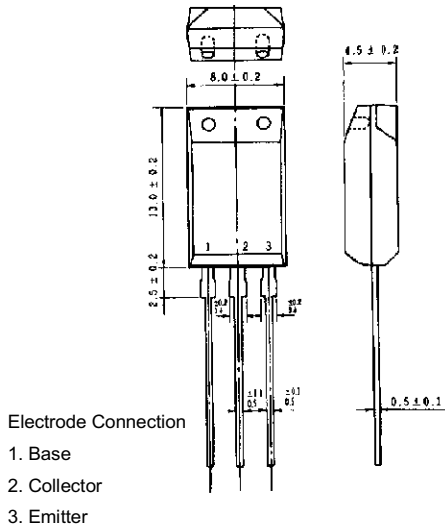
\* Pulse test  $PW \leq 350 \mu s$ , duty cycle  $\leq 2\%$

**hFE CLASSIFICATION**

Marking	M	L	K
$h_{FE2}$	100 to 200	150 to 300	200 to 400

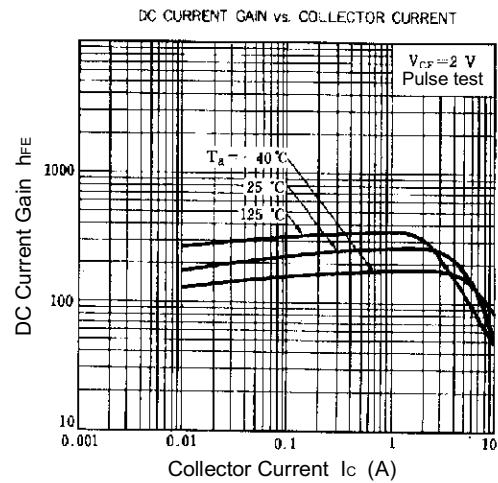
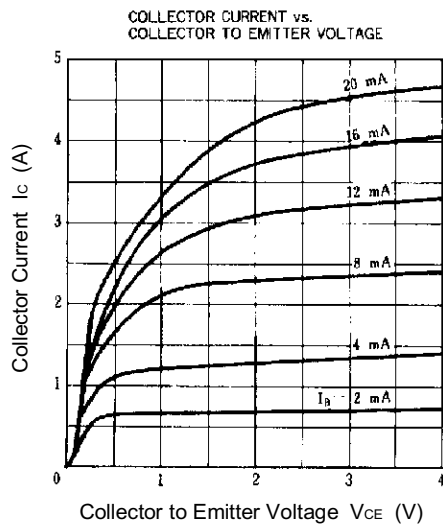
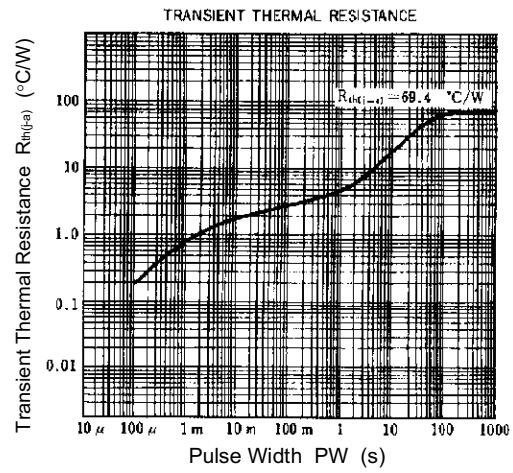
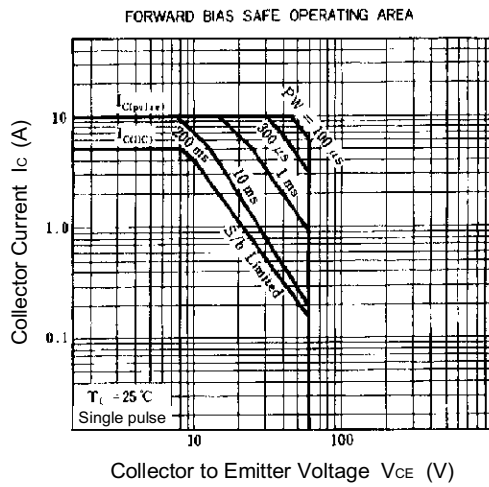
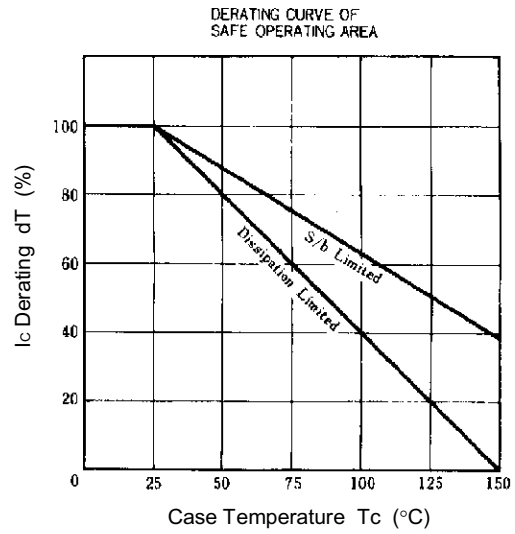
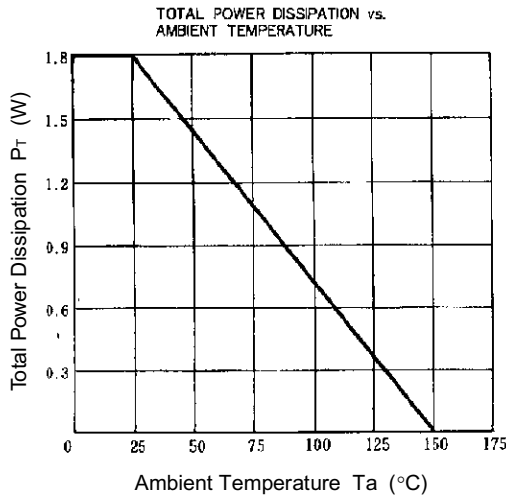
**PACKAGE DRAWING (UNIT: mm)**

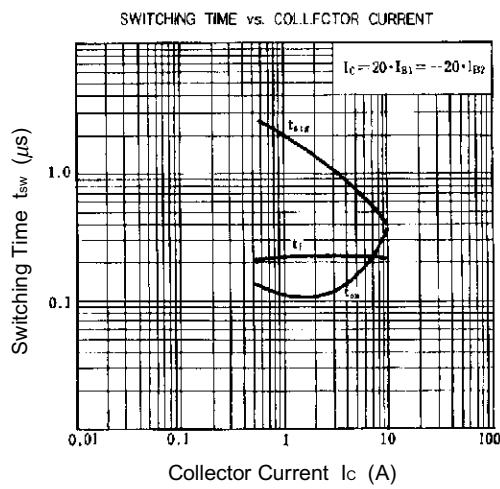
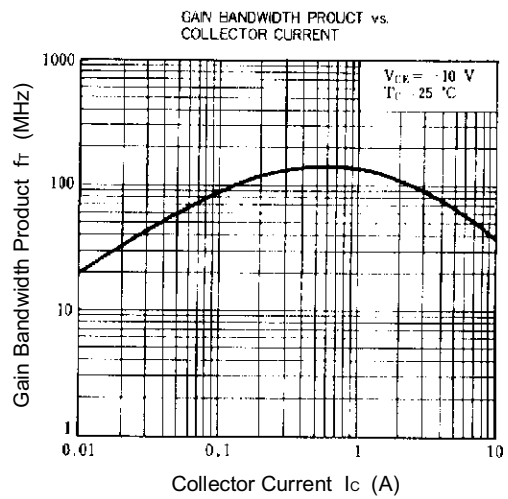
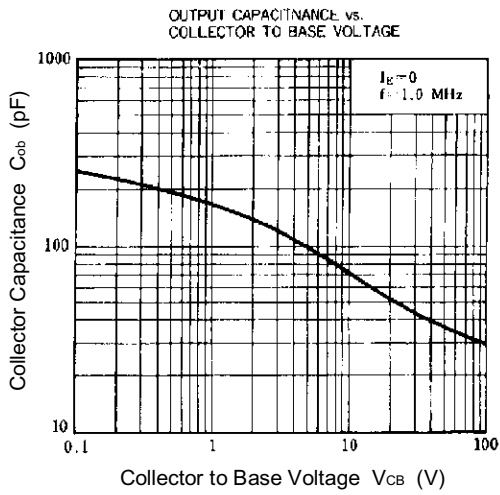
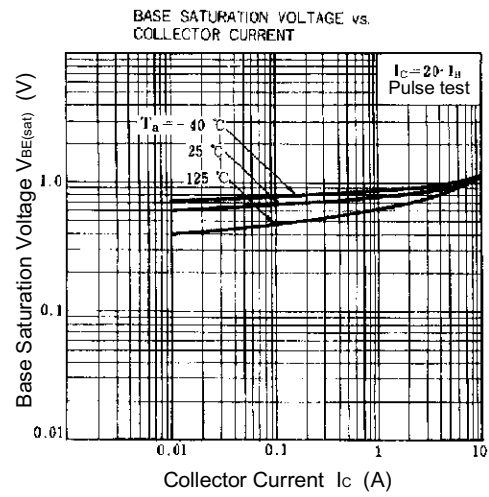
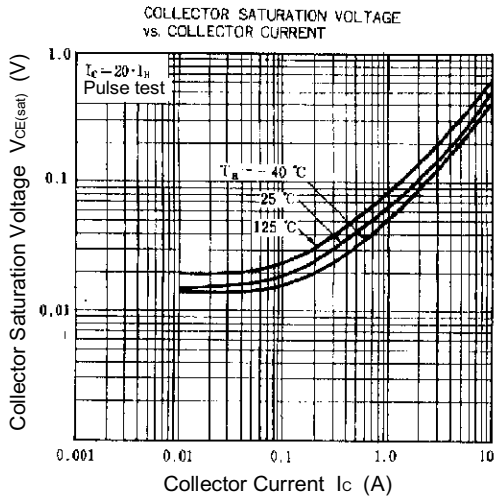
**TAPING SPECIFICATION**



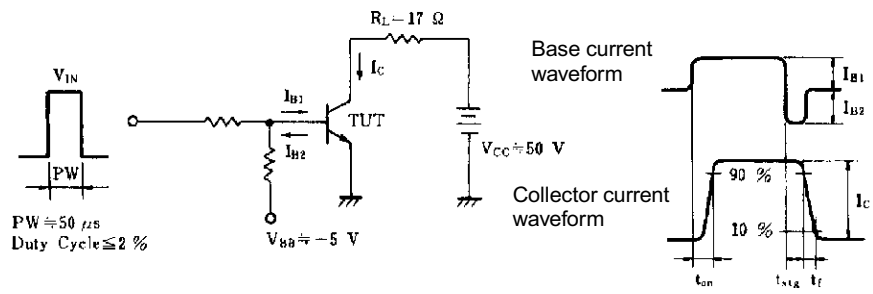
$A_1$	$8.0 \pm 0.2$
A	$13.0 \pm 0.2$
$D_0$	$\phi 4.0 \pm 0.2$
d	$0.5 \pm 0.1$
$F_1$	$2.5^{+0.4}_{-0.1}$
$F_2$	$2.5^{+0.4}_{-0.1}$
H	20.0 MAX.
$H_0$	$16.0 \pm 0.5$
$H_1$	32.2 MAX.
$\Delta h$	$0 \pm 1.0$
$\rho_1$	2.5 MIN.
P	$12.7 \pm 1.0$
$P_0$	$12.7 \pm 0.3$
$P_2$	$6.35 \pm 0.5$
$\Delta P$	$0 \pm 1.3$
T	$4.5 \pm 0.2$
W	$18.0^{+1.0}_{-0.5}$
$W_0$	5.0 MIN.
$W_1$	$9.0 \pm 0.5$
$W_2$	0.7 or less

TYPICAL CHARACTERISTICS (Ta = 25°C)





SWITCHING TIME ( $t_{on}$ ,  $t_{stg}$ ,  $t_f$ ) TEST CIRCUIT



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